Thin Film Center-Tapped Resistors





Product may not be to scale

The CTQ series resistor chips offer a wide resistance range with lower shunt capacitance than can be offered with the silicon based resistors but only at a lower power level.

The CTQ offers the designer flexibility in use as either a single value resistor or as two resistor with a center tap feature.

The CTQs six bonding pads allows the user increased layout flexibility.

The CTQs are manufactured using Vishay Electro-Films (EFI) sophisticated thin film equipment and manufacturing technology. The CTQs are 100% electrically tested and visually inspected to MIL-STD-883.

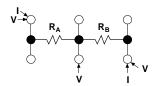
APPLICATIONS

The CTQ center-tapped resistor chips are used mainly in feedback circuits of amplifiers where ratio matching, low shunt capacitance and tracking between two resistors is critical.

For low values, the resistance of the six bonding pad configuration can vary, depending on the method of measurement used. Vishay EFI measures low-value resistors by the four-wire Kelvin technique.

FEATURES

- · Center tap feature
- · Chip size: 0.030 inches square
- Resistance range total: 10Ω to $1M\Omega$
- · Resistor material: Tantalum nitride, self-passivating
- Moisture resistant
- · Quartz substrate
- Low shunt capacitance < 0.1pF



TEMPERATURE COEFFICIENT OF RESISTANCE, VALUES AND TOLERANCES **Tightest Standard Tolerance Available** 0.5% 0.1% **PROCESS CODE** CLASS H* **CLASS K*** \pm 25ppm/ $^{\circ}$ C 102 132 100 ± 50ppm/°C 130 ± 100ppm/°C 101 131 *MIL-PRF-38534 10 Ω 25Ω 100 Ω 360Κ Ω 620Κ Ω 1Μ Ω

STANDARD ELECTRICAL SPECIFICATIONS	
PARAMETER	
TCR tracking between halves (R _A , R _B)	± 2ppm/°C*
Center tap ratio, R _A /R : Tolerance	1 ± 1% standard
Noise, MIL-STD-202, Method 308 100Ω - $250k\Omega$ < 100Ω or > $251k\Omega$	- 35dB typical - 20dB typical
Moisture resistance, MIL-STD-202, Method 106	$\pm0.5\%$ maximum Δ R/R
Stability, 1000 hours, + 125°C, 30mW	± 0.25% maximum ΔR/R
Operating temperature range	- 55°C to + 125°C
Thermal shock, MIL-STD-202, Method 107, Test condition F	± 0.1% maximum ΔR/R
High temperature exposure, + 150°C, 100 hours	± 0.2% maximum ΔR/R
Dielectric voltage breakdown	400V
Insulation resistance	10 ¹² minimum
Operating voltage	200V
DC power rating at + 70°C (derated to zero at + 175°C)	60mW
5 x rated power short-time overload, + 25°C, 5 seconds	$\pm0.25\%$ maximum Δ R/R

*5ppm/°C for R < 100. 20ppm/°C for R < 20

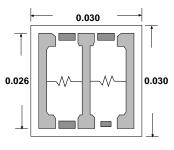
VISHAY ELECTRO-FILMS • FRANCE +33.4.93.37.28.24 FAX: +33.4.93.37.27.31 • GERMANY +49.9287.710 FAX: +49.9287.70435 • ISRAEL +972.3.557.0945 FAX: +972.3.558.9121 • ITALY + 39.2.300.11911 FAX: +39.2.300.11999 • JAPAN +81.42.729.0661 FAX: +81.42.729.3400 • SINGAPORE +65.788.6668 FAX: +65.788.0988 • SWEDEN +46.8.594.70590 FAX: +46.8.594.70581 • UK +44 191 514 8237 FAX: +44 1953 457 722 • USA: (401) 738-9150 FAX: (401) 738-4389



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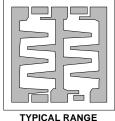
Vishay Electro-Films

DIMENSIONS in inches

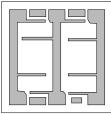


STANDARD CONFIGURATION

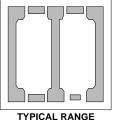
Six locations. All pads 0.005 x 0.005 inches



10 Ω - 26.9 Ω

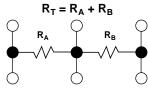


TYPICAL RANGE 27 Ω - 99 Ω



100 Ω - 1M Ω

SCHEMATIC



MECHANICAL SPECIFICATIONS in	CHANICAL SPECIFICATIONS in inches				
PARAMETER					
Chip size	0.030 x 0.030 ± 0.002 (0.762 x 0.762 ± 0.05mm)				
Chip thickness	$0.010 \pm 0.003 \ (0.254 \pm 0.05 \text{mm})$				
Chip substrate material	Quartz				
Resistor material	Tantalum Nitride, self-passivating				
Bonding pad size	0.005 x 0.005 (0.127 x 0.127mm)				
Number of pads	6				
Pad material	10kÅ minimum aluminum				
Backing	None, lapped quartz				

OPTIONS:

Alphanumeric part marking, up to six characters Gold bonding pads, 15kÅ minimum Center-tap ratio tolerances to 0.05% 1 to 10 ohm values available Contact Applications Engineer

ORDERING INFORMATION									
Example: 100% visualled, 10kΩ, ± 1%, ± 100ppm/°C TCR, Aluminum Pads, Class H									
P/N:	W INSPECTION /PACKAGING	CTQ PRODUCT FAMILY	101 PROCESS CODE	1000 RESISTANCE VALUE	1 MULTIPLIER CODE	F TOLERANCE CODE			
pa loa X : ins	= 100% visually ins ints per MIL-STD-88 aded in matrix tray = Sample, visually spected loaded in m interview (4% AQL)	3	See Process Code table	Use first 4 significant digits of resistance (Rt)	D = 0.0001 C = 0.001 B = 0.01 A = 0.1 0 = 1 1 = 10 2 = 100 3 = 1000 4 = 10000	B =0.1% C =0.2% D = 0.5% F = 1.0% G = 2.0% H = 2.5% J = 5.0% K = 10% M = 20% L = 25%			

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